BOURNS®

- 7 A Continuous Collector Current
- 15 A Peak Collector Current
- 60 W at 25°C Case Temperature

TO-220 PACKAGE (TOP VIEW)

Pin 2 is in electrical contact with the mounting base.

3

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT		
Callecter base veltage (L = 0)	BU406	V	400	V	
Collector-base voltage (I _E = 0)	BU407	V _{CBO}	330	V	
Collector without Ar. CAO		V	400	V	
Collector-emitter voltage (V _{BE} = -2 V)	BU407	V _{CEX}	330	V	
Collector emitter voltage (L = 0)	BU406	V	200	V	
Collector-emitter voltage (I _B = 0)	BU407	V _{CEO}	150	V	
Emitter-base voltage	V_{EB}	6	V		
Continuous collector current	I _C	7	Α		
Peak collector current (see Note 1)	I _{CM}	15	Α		
Continuous base current	I _B	4	Α		
Continuous device dissipation at (or below) 25°C case temperature			60	W	
Operating junction temperature range	T _j	-55 to +150	°C		
Storage temperature range	T _{stg}	-55 to +150	°C		

NOTE 1: This value applies for $t_p \le 10$ ms, duty cycle $\le 2\%$.



electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS				MIN	TYP	MAX	UNIT	
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C =	30 mA	I _B = 0			140			٧
I _{CES}	Collector-emitter cut-off current	V _{CE} = V _{CE}	330 V 250 V 200 V 250 V	$V_{BE} = 0$	T _C = 150°C T _C = 150°C	BU406 BU407 BU406 BU407 BU406 BU407			5 5 0.1 0.1 1	mA
I _{EBO}	Emitter cut-off current	V _{EB} =	6 V	I _C = 0					1	mA
h _{FE}	Forward current transfer ratio	V _{CE} = V _{CE} =	10 V 10 V	$I_{C} = 4 A$ $I_{C} = 0.5 A$	(see Notes 2 ar	nd 3)	12 20			
V _{CE(sat)}	Collector-emitter saturation voltage	I _B =	0.5 A	I _C = 5 A	(see Notes 2 ar	nd 3)			1	٧
V _{BE(sat)}	Base-emitter saturation voltage	I _B =	0.5 A	I _C = 5 A	(see Notes 2 ar	nd 3)			1.2	٧
f _t	Current gain bandwidth product	V _{CE} =	5 V	I _C = 0.5 A	f = 1 MHz	(see Note 4)		6		MHz
C _{ob}	Output capacitance	V _{CB} =	20 V	I _E = 0	f = 1 MHz			60		pF

NOTES: 2. These parameters must be measured using pulse techniques, t_p = 300 μ s, duty cycle \leq 2%.

thermal characteristics

PARAMETER				MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			2.08	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			70	°C/W

inductive-load-switching characteristics at 25°C case temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
ts	Storage time	I _C = 5 A	$I_{R(ond)} = 0.5A$	(see Figures 1 and 2)		2.7		μs
t _(off)	Turn off time	IC - 2 Y	$I_{B(end)} = 0.5A$	(See Figures Faria 2)			750	ns

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

^{3.} These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

^{4.} To obtain f_t the $[h_{FE}]$ response is extrapolated at the rate of -6 dB per octave from f = 1 MHz to the frequency at which $[h_{FE}] = 1$.

PARAMETER MEASUREMENT INFORMATION

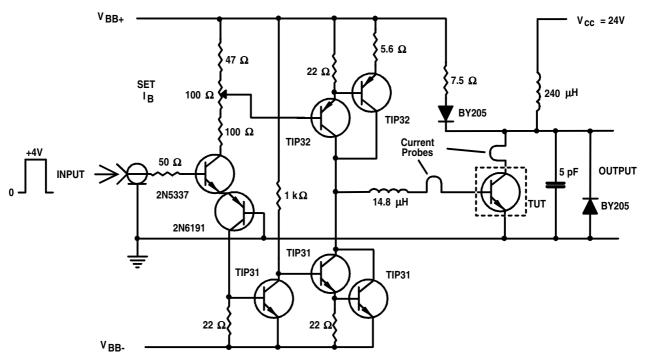


Figure 1. Inductive-Load Switching Test Circuit

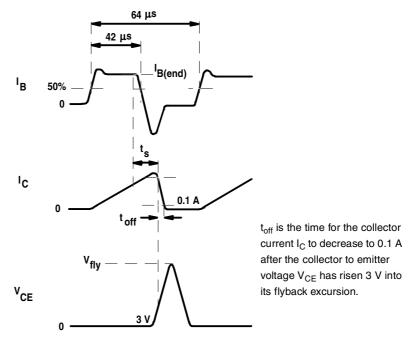
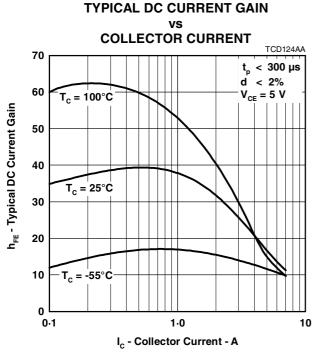


Figure 2. Inductive-Load Switching Waveforms

TYPICAL CHARACTERISTICS



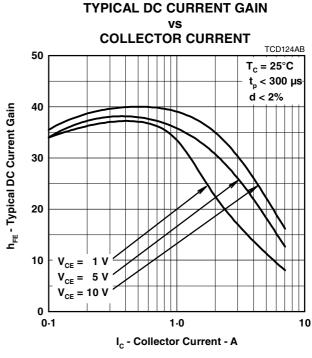
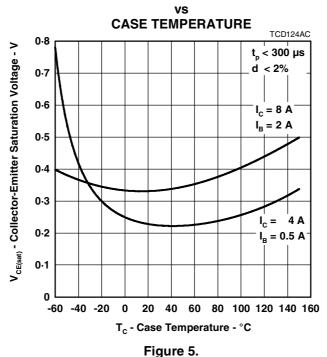


Figure 3.

Figure 4.

COLLECTOR-EMITTER SATURATION VOLTAGE



MAXIMUM SAFE OPERATING REGIONS

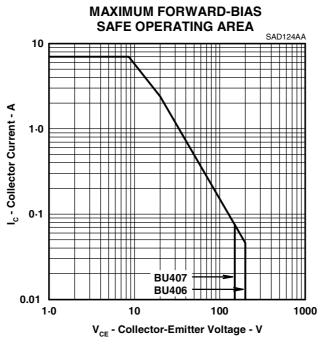


Figure 6.

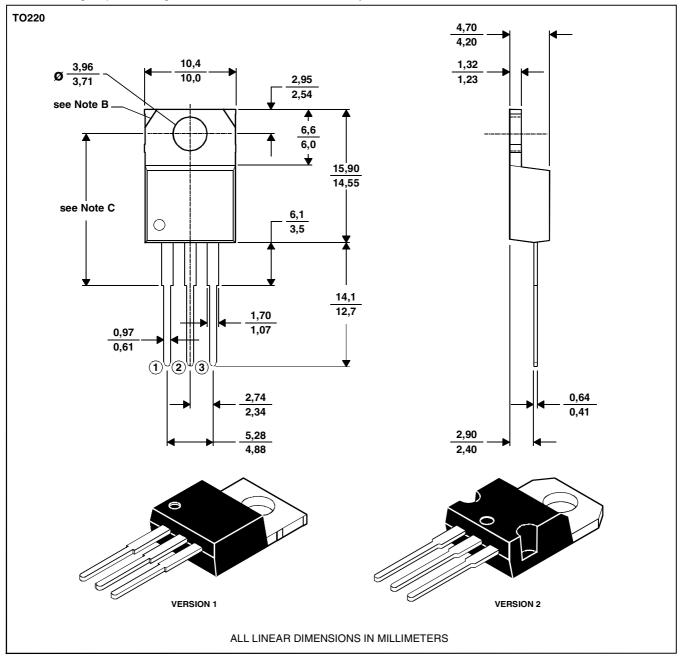


MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTES: A. The centre pin is in electrical contact with the mounting tab.

- B. Mounting tab corner profile according to package version.
- C. Typical fixing hole centre stand off height according to package version.

Version 1, 18.0 mm. Version 2, 17.6 mm.

MDXXBE